

L Number	Hits	Search Text	DB	Time stamp
18	4	(laser near diode) and (third near clad\$4) and active and contact and electrode and (injection near3 stripe)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/25 09:36
19	6	(laser) and (third near clad\$4) and active and contact and electrode and (injection near3 stripe)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/25 10:08
20	2	(laser) and (third near clad\$4) and active and contact and electrode and (injection near3 stripe) and ((electrode or contact) near (second near clad\$4))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/25 10:02
21	0	(laser) and (third near clad\$4) and active and contact and electrode and (injection near3 stripe) and ((electrode) near (second near clad\$4))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/25 10:04
22	34	(laser) and ((electrode) near (second near clad\$4))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/25 10:05
23	23	(laser) and ((electrode) near (second near clad\$4))	USPAT	2003/08/25 10:05
24	6	(laser) and (third near clad\$4) and active and (contact near (layer or region or medium)) and electrode and (injection near3 stripe)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/25 10:15
26	2	(laser) and (third near clad\$4) and active and (contact near (layer or region or medium)) and (electrode with clad\$4) and (injection near3 stripe)	USPAT	2003/08/25 10:15
-	33	(laser near diode) and clad\$4 and active and contact and electrode and (injection near3 stripe) and voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/25 09:31
-	26	((laser near diode) and clad\$4 and active and contact and electrode and (injection near3 stripe) and voltage) and 372/\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/02 14:55
-	53	laser and clad\$4 and active and contact and electrode and (injection near3 stripe) and voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 09:01
-	10	laser and clad\$4 and active and contact and electrode and (injection near stripe) and voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 06:12
-	29	laser and clad\$4 and active and contact and electrode and (injection near2 stripe) and voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 08:47

-	2	laser and clad\$4 and active and contact and electrode and (injection near2 stripe) and voltage and (etching near stop near (layer or region or medium or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:07
-	2	laser and clad\$4 and active and contact and electrode and (injection near2 stripe) and voltage and (etch\$4 near stop)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:06
-	12	laser and clad\$4 and active and contact and electrode and (injection near2 stripe) and voltage and (etch\$4 near (layer or region or medium or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 08:57
-	1	((laser and clad\$4 and active and contact and electrode and (injection near2 stripe) and voltage and (etch\$4 near (layer or region or medium or film))) and third near clad	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 08:57
-	1	((laser and clad\$4 and active and contact and electrode and (injection near2 stripe) and voltage and (etch\$4 near (layer or region or medium or film))) and third near clad\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 09:09
-	364	((laser or diode) with (ridge or stripe)) and clad\$4 and active and contact and electrode and voltage and 372/46	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 09:06
-	137	((laser NEAR diode) with (ridge or stripe)) and clad\$4 and active and contact and electrode and voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 09:07
-	12	((laser NEAR diode) with (ridge or stripe)) and clad\$4 and active and contact and electrode and voltage) and third near clad\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 09:21
-	5	((laser NEAR diode) with (ridge or stripe)) and clad\$4 and active and contact and electrode and voltage) and third near clad\$4) and 372/46	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 13:02
-	60	((laser NEAR diode) with (ridge or stripe)) and clad\$4 and active and contact and electrode and voltage) and 372/46	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 14:04
-	111	((laser NEAR diode) with (ridge or stripe)) and (clad\$4 near (layer or region or medium or film)) and (active near (layer or region or medium or film)) and (contact near (layer or region or medium or film)) and electrode and 372/46	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 14:06
-	52	((laser NEAR diode) with (ridge or stripe)) and (clad\$4 near (layer or region or medium or film)) and (active near (layer or region or medium or film)) and (contact near (layer or region or medium or film)) and electrode and 372/46) and voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 14:10

-	10	((laser NEAR diode) with (ridge or stripe)) and (clad\$4 near (layer or region or medium or film)) and (active near (layer or region or medium or film)) and (contact near (layer or region or medium or film)) and electrode and 372/46) and third near clad\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 14:10
-	0	clad\$ and laesr near diode and (etch\$4 near stop)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:06
-	320	clad\$ and (laser near diode) and (etch\$4 near stop)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:07
-	258	clad\$ and (laser near diode) and (etch\$4 near stop near layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:08
-	5	laser and clad\$4 and active and contact and electrode and (injection near2 stripe) and (etching near stop near (layer or region or medium or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:08
-	166	laser and clad\$4 and active and contact and electrode and (ridge or stripe) and (etching near stop near (layer or region or medium or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:40
-	98	((laser and clad\$4 and active and contact and electrode and (ridge or stripe) and (etching near stop near (layer or region or medium or film))) and 372/46	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:33
-	1	((laser and clad\$4 and active and contact and electrode and (ridge or stripe) and (etching near stop near (layer or region or medium or film))) and 372/46) and saturatable near absorption	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:35
-	8	((laser and clad\$4 and active and contact and electrode and (ridge or stripe) and (etching near stop near (layer or region or medium or film))) and 372/46) and saturable near absorption	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:35
-	1	(laser near diode) and clad\$4 and active and contact and electrode and (ridge or stripe) and (etching near stop near (layer or region or medium or film)) and saturable near absorption and 372/46	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 10:03
-	2	(laser near diode) and clad\$4 and active and contact and electrode and (ridge or stripe) and (etching near stop near (layer or region or medium or film)) and saturable near absorption	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 11:10
-	0	(laser near diode) and clad\$4 and active and (ridge or stripe) and (etching near stop near (layer or region or medium or film)) and saturable near absorption and (grating near2 bars) and ((feed adj back) or feedback)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 11:09

-	0	(laser near diode) and clad\$4 and active and saturable near absorption and (grating near2 bars) and ((feed adj back) or feedback)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 11:09
-	0	((laser near diode) and clad\$4 and active and contact and electrode and (ridge or stripe) and (etching near stop near (layer or region or medium or film)) and saturable near absorption) and grating near2 bar	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 11:09
-	1091	grating near2 bar	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 11:09
-	1091	grating near2 bars	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 11:09
-	742	grating near bars	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 11:10
-	5	(laser near diode) and clad\$4 and active and (grating near2 bars)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/15 07:03
-	4	laser and (clad with (current near injection near stripe)) and electrode and contact	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/15 07:05
-	81	laser and (clad with (current near injection)) and electrode and contact	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/15 07:06
-	123	laser and (clad with (current near injection)) and electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/15 07:43
-	298	laser and (clad\$4 with (current near injection)) and electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/15 07:45
-	298	laser and (clad\$4 with (current near injection)) and electrode and clad\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/15 08:50
-	2777	372/46.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/15 08:50

-	131	372/46.ccls. and (clad\$4 with (current near injection)) and electrode and clad\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/15 09:03
-	95	372/46.ccls. and (clad\$4 with (current near injection)) and electrode and clad\$4	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/08/15 09:25
-	358	372/46.ccls. and (current near injection) and electrode and clad\$4	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/08/15 09:26
-	263	(372/46.ccls. and (current near injection) and electrode and clad\$4) not (372/46.ccls. and (clad\$4 with (current near injection)) and electrode and clad\$4)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/08/15 09:26